



# Terahertz ellipsometry using electron-beam based sources

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MoP.99

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## Our message

• THz ellipsometry opens a new pathways for the investigation of the properties complex optical materials needed as building blocks for next generation nanoelectronics

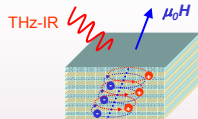
• in combination with external magnetic fields THz generalized ellipsometry is a powerful tool to determine free charge carrier properties and study quantum confinement effects in semiconductors and semimetals

• electron beam based sources are readily available (Synchrotron radiation, Smith-Purcell radiation) and offer sufficient radiation in the THz frequency domain

New THz materials preparation and analysis Center at UNL: TheMPAC

## Motivation: THz spectroscopic ellipsometry

### 2D Semiconductor & Semimetal

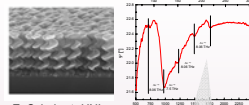


quantum confinement-effects in low dimensional systems

Generalized ellipsometry in combination with external magnetic fields:

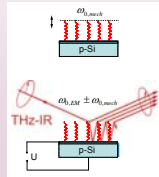
- Semiconductors: unbound charge carrier resonances in spatially confined structures in the THz frequency domain
- Highly oriented pyrolytic graphite: Landau level transitions, electron and hole contributions

### Complex metamaterials



E. Schubert, UNL

resonances in a sculptured Al thin Film on Si



new detector structures: quantum opto-mechanical couplers with Eigenresonances in the THz-IR domain

### 3D Nanostructure Networks



D. E. Scharrett and R. E. Garrison Am. Log. 37 (2005)

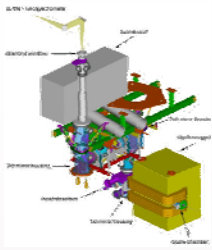
- future nanoelectronics will be assembled from nano-sized thin film structures and metamaterials
- new physical phenomena in these building blocks like quantum confinement and surface effects will alter the physical properties and need to be studied

optical metrology tools needed

optical and mechanical Eigenresonances of these material fall in the THz domain

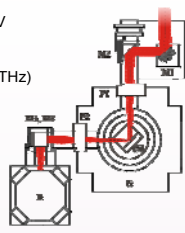
## Synchrotron radiation

### IRIS-beam line at BESSY II



W.B. Peatman and U. Schade, Rev. Scie. Inst. 72, 1620 (2001)  
U. Schade et al. Rev. Scie. Inst. 73, 1563 (2002)

### Experimental setup

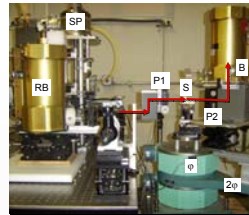


T. Hofmann et al. Rev. Scie. Inst. 77, 63902 (2006)

- electron energy of 1.7 GeV
- beam current ~300 mA
- $\lambda = \sim 30$  to  $3000 \text{ cm}^{-1}$  (333 to  $3.25 \mu\text{m}$ , 0.9 to 90 THz)

## Smith-Purcell free electron laser

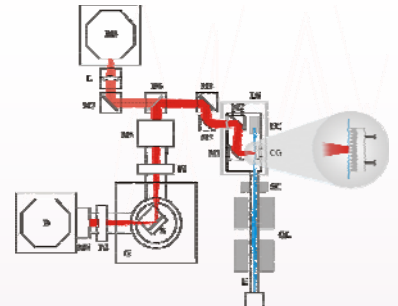
### Smith-Purcell effect



### Smith-Purcell Source:

- electron energy: 20-38 keV
- grating type: rectangular Cu-grating (25  $\mu\text{m}$  wide, 100  $\mu\text{m}$  deep slots)

### Experimental setup

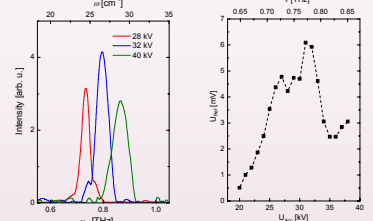
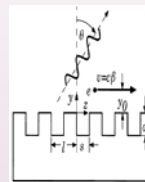


T. Hofmann et al. Rev. Scie. Inst. (in submission)

Electromagnetic radiation is emitted if an electron beam passes a periodic metal grating:

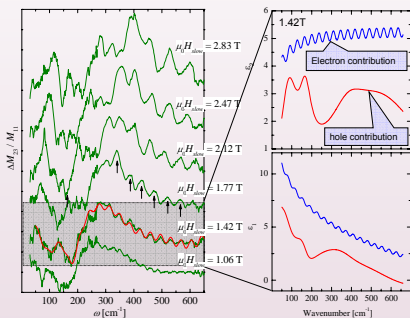
$$\lambda = \frac{L}{|\beta|} (1 - \sin \theta)$$

- $\lambda$  – output wavelength
- $\beta$  – electron velocity
- $\theta$  – emission angle



typical output intensity spectra and signal level at the reference Si-Bolometer, the source is operated below the threshold to superradiant emission

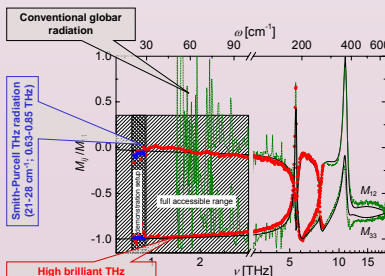
## Highly oriented pyrolytic graphite



Conclusion: Landau transitions should originate from unoccupied valence band states!

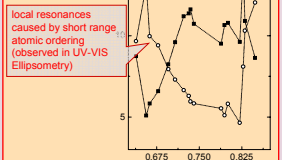
## Zn<sub>0.87</sub>Mn<sub>0.13</sub>Se

ZnMnSe – a diluted magnetic semiconductor is employed as an example system



T. Hofmann et al. Appl. Phys. Lett. 77, 63902 (2006)

## First optical constants for ZnMnSe in the THz domain!



local resonances caused by short range atomic ordering (observed in UV-VIS Ellipsometry)

Higher resolution measurements needed!